ISSN 0039-6028

surface science

MASTER INDEX

A journal devoted to the physics and chemistry of interfaces

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SUSCA MI 261–270, 1–202 (1992)

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Master Index to Volumes 261–270

NORTH-HOLLAND

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ISSN: **0887-1949**
Volume 7, Issues 1-12
Institutional Rate: $395.00
Personal Rate: $100.00
(Postage and handling outside North America $35.00.)

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